CEL -Power Electronics and Electromechanical Systems T009

Thursday, 23/11/2017 08:30-11:30 AM

WORKFORCE DEVELOPMENT AUTHORITY

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# ADVANCED LEVEL NATIONAL EXAMINATIONS, 2017, TECHNICAL AND PROFESSIONAL STUDIES 

## EXAM TITLE: <br> POWER ELECTRONICS AND ELECTROMECHANICAL SYSTEMS <br> OPTION: Computer Electronics (CEL) <br> DURATION: 3 hours

## INSTRUCTIONS:

The paper is composed of three (3) main Sections as follows:
Section I: Fifteen (15) compulsory questions. 55 marks
Section II: Attempt any three (3) out of five questions. $\mathbf{3 0}$ marks
Section III: Attempt any one (1) out of three questions. 15 marks

## Note:

Every candidate is required to carefully comply with the above instructions. Penalty measures will be applied on their strict consideration.

1. Explain the linear circuit elements in electrical circuit and give their examples.
2. Define the following terms:
a. Controllers
b. Sensors
c. Filters
d. Inverter

4 marks
03. Can an ordinary diode be used as a zener diode? Justify your answer.

## 3 marks

4. State the Current-voltage Switching classification.

4 marks
05. What are power converters that utilize natural commutation? 4 marks
06. The current waveform passing through a diode switch in a switch mode power supply application is shown in Figure below. Find the average, rms, and the peak current.

3 marks

07. Which features must semiconductor possess in order to operate as an ideal switch?

5 marks
08. What are characteristics of The Practical Switch?

4 marks
09. What is the name of the semiconductor symbol shown below and put the names on its terminals

2 marks

10. List at least four Applications of uni-junction transistor (UJT). 4 marks
11. Classify choppers depending on the voltage output.

3 marks
12. Which precautions that must be taken when triggering a Triac?
13. Explain the Thyristor commutation techniques.

5 marks
14. What can happen if diodes are connected in:
a. Series?
b. Parallel?

4 marks
15. Give at least four reasons which may cause the switching devices fail.

4 marks
Section II. Choose and answer any three (3) questions.
30 marks
16. A Power MOSFET has $I_{D S S}=2 m A, R_{D S(O N)}=0.3 \Omega$, duty cycle $\mathrm{d}=50 \%, \mathrm{I}_{\mathrm{D}}=$ $6 \mathrm{~A}, \mathrm{~V}_{\mathrm{DS}}=100 \mathrm{~V}, \mathrm{t}_{\mathrm{r}}=100 \mathrm{~ns}$ and $\mathrm{t}_{\mathrm{f}}=200 \mathrm{~ns}$. If the frequency of switching is 40 KHz , then find:
i) on-state loss
ii) off-state loss
iii) turn-on switching loss
iv) turn-off switching loss.

10 marks
17. i) A power transistor has $V_{c c}=208 \mathrm{~V}, R_{c}=20 \Omega$;
$V_{C E(S A T)}=0.9 \mathrm{~V} ; V_{B E(S A T)}=1.1 \mathrm{~V}$ and $\beta=10$
Find :
a) $I_{C} ; I_{B}$
b)The power loss in collector $\left(\mathrm{P}_{c}\right)$.
c) Power loss in base $\left(\mathrm{P}_{B}\right)$
ii) Draw construction of SCR using two transistor models.

10 marks
18. What is IGBT? Draw the switching characteristics of IGBT. 10 marks
19. The BJT is specified to have a range of 8 to 40 .the load resistance in $\mathrm{R}_{\mathrm{e}}=11 \Omega$. The DC supply voltage is $\mathrm{V}_{\mathrm{cc}}=200 \mathrm{~V}$ and input voltage to the base circuit is $\mathrm{V}_{\mathrm{B}}=10 \mathrm{~V}$.if $V_{\text {CE(SAT) }}=1.0 \mathrm{~V}$ and $V_{B E(S A T)}=1.5 \mathrm{~V}$.

Find :
a) The value of $R_{B}$ that results in saturation with a overdrive factor of 5 .
b) The forced $\beta_{f}$.
c) The power loss PT in the transistor.

10 marks
20. a) In figure below, the switch is closed. if the triac has fired, what is the current through $50 \Omega$ resistor when:
i) Triac is ideal
ii) Triac has a drop of 1 V

b) A d.c. to d.c. chopper operates from a 48 V battery source into a resistive load of $24 \Omega$. The frequency of the chopper is set to 250 Hz . Determine the average and rms load current and load power values when chopper on-time is 1 ms .

10 marks
15 marks

Section III. Choose and answer any one (1) question.
21. Briefly, explain the Modes of Operation in silicon controlled rectifier (SCR).
22. A separately excited DC motor has the following parameters: 220 V , 100 A and 1450 rpm . Its armature has a resistance of $0.1 \Omega$. In addition, it is supplied from a 3 phase fully-controlled converter connected to a 3phase AC source with a frequency of 50 Hz and inductive reactance of $0.5 \Omega$ and 50 Hz . At transport factor $(\mathrm{a})=0$, the motor operation is at rated torque and speed. Assume the motor brakes re-generatively using the reverse direction at its rated speed. Calculate the maximum current under which commutation is not affected.
23. Explain the formation of a potential barrier in a p-n junction of a semiconductor.

